	Туре	Hits	Search Text	DBs
1			"20040113152"	US-PGPUB; USPAT;
	BRS	2		EPO; JPO;
				DERWENT; IBM_TDB
				US-PGPUB; USPAT;
2	BRS	1854956	vertical	EPO; JPO;
				DERWENT; IBM TDB
			tft on /thin add film add	US-PGPUB; USPAT;
3	BRS	68552	tft or (thin adj film adj	EPO; JPO;
			transistor)	DERWENT; IBM TDB
	BRS	586	S2 near3 S3	US-PGPUB; USPAT;
4				EPO; JPO;
}				DERWENT; IBM TDB
				US-PGPUB; USPAT;
5	BRS	292702	"257"/\$.ccls.	EPO; JPO;
	_		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	DERWENT; IBM TDB
			"438"/\$.ccls.	US-PGPUB; USPAT;
6	BRS	159803		EPO; JPO;
				DERWENT; IBM TDB
			S4 and (S5 or S6)	US-PGPUB; USPAT;
7	BRS	278		EPO; JPO;
				DERWENT; IBM TDB
				US-PGPUB; USPAT;
8	BRS	208	S2 adj2 S3	EPO; JPO;
				DERWENT; IBM TDB
	<b>-</b>			US-PGPUB; USPAT;
9	BRS	362820	S5 or S6	EPO; JPO;
				DERWENT; IBM TDB
	-			US-PGPUB; USPAT;
10	BRS	104	S8 and S9	EPO; JPO;
				DERWENT; IBM TDB
	BRS	2	"6391471"	US-PGPUB; USPAT;
11				EPO; JPO;
				DERWENT; IBM TDB
	-			US-PGPUB; USPAT;
12	BRS	104	S8 not S10	EPO; JPO;
				DERWENT; IBM TDB
	BRS	6	"4996573"	US-PGPUB; USPAT;
13				EPO; JPO;
				DERWENT; IBM TDB
	1			US-PGPUB; USPAT;
14	BRS	219	257/135	EPO; JPO;
				DERWENT; IBM TDB
	BRS	2604		US-PGPUB; USPAT;
15			257/72	EPO; JPO;
				DERWENT; IBM TDB
	BRS	1457	257/328	US-PGPUB; USPAT;
16				EPO; JPO;
				DERWENT; IBM TDB

	Time Stamp
1	2004/12/07 15:52
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3	2004/12/07 15:53
4	2004/12/07 15:54
5	2004/12/07 15:55
6	2004/12/07 15:56
7	2004/12/07 15:57
8	2004/12/07 15:57
9	2004/12/07 15:58
10	2004/12/07 16:50
11	2004/12/07 16:36
12	2004/12/07 17:11
13	2004/12/07 17:12
14	2004/12/07 17:29
15	2004/12/07 17:31
16	2004/12/07 17:35

	Туре	Hits	Search Text	DBs
				US-PGPUB; USPAT;
17	BRS	1195	257/329	EPO; JPO;
				DERWENT; IBM_TDB
				US-PGPUB; USPAT;
18	BRS	54318	substrate near4 plastic	EPO; JPO;
				DERWENT; IBM_TDB
				US-PGPUB; USPAT;
19	BRS	977	S3 same S18	EPO; JPO;
				DERWENT; IBM_TDB
				US-PGPUB; USPAT;
20	BRS	13189	S18 near4 glass	EPO; JPO;
				DERWENT; IBM_TDB
				US-PGPUB; USPAT;
21	BRS	794	S20 near4 silicon	EPO; JPO;
				DERWENT; IBM_TDB
				US-PGPUB; USPAT;
22	BRS	53	S3 same S21	EPO; JPO;
				DERWENT; IBM_TDB
				US-PGPUB; USPAT;
23	BRS	9861	organic near3 semiconductor	EPO; JPO;
<u> </u>				DERWENT; IBM TDB
				US-PGPUB; USPAT;
24	BRS	638	S3 same S23	EPO; JPO;
	ļ			DERWENT; IBM TDB
0.5	22.0	206	7 700	US-PGPUB; USPAT;
25	BRS	396	S3 near7 S23	EPO; JPO;
				DERWENT; IBM TDB
0.5	777	ے م		US-PGPUB; USPAT;
26	BRS	35	S25 near7 silicon	EPO; JPO;
L				DERWENT; IBM_TDB

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17	2004/12/07 18:27
18	2004/12/07 18:29
19	2004/12/07 18:29
20	2004/12/07 18:29
21	2004/12/07 18:29
22	2004/12/07 18:53
23	2004/12/07 18:53
24	2004/12/07 18:53
25	2004/12/07 18:56
26	2004/12/07 18:56